SCCS019D - MAY 1994 - REVISED NOVEMBER 2001

- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Version of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- 64-mA Output Sink Current
   32-mA Output Source Current
- 3-State Outputs

#### **Q OR SO PACKAGE** (TOP VIEW) S 16 NCC 15 OE $I_{0a}$ 14 | I<sub>0c</sub> I<sub>1a</sub> [] 3 Y<sub>a</sub> [] 4 13 I<sub>1c</sub> I<sub>0b</sub> [] 5 12 Y<sub>C</sub> 11 🛮 I<sub>0d</sub> 6 $I_{1b}$ 10 | I<sub>1d</sub> Y<sub>b</sub> [] 7 GND 8 9]] Y<sup>d</sup>

### description

The CY74FCT257T has four identical two-input multiplexers that select four bits of data from two sources under the control of a common data-select (S) input. The  $I_0$  inputs are selected when S is low, and the  $I_1$  inputs are selected when S is high. Data at the output is noninverted.

The CY74FCT257T is a logic implementation of a four-pole, two-position switch, where the position of the switch is determined by the logic levels at S. Outputs are in the high-impedance state when the output-enable ( $\overline{OE}$ ) input is high.

All but one device must be in the high-impedance state to avoid currents exceeding the maximum ratings if outputs are tied together.  $\overline{OE}$  inputs must ensure that there is no overlap when outputs of 3-state devices are tied together.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### PIN DESCRIPTION

NAME	DESCRIPTION
I	Data inputs
S	Common data-select input
ŌĒ	Output-enable input (active low)
Υ	Data outputs



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### **ORDERING INFORMATION**

T <sub>A</sub>	PACI	KAGE†	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP – Q		4.3	CY74FCT257CTQCT	FT257-3
	SOIC - SO	Tube	4.3	CY74FCT257CTSOC	F0T0570
–40°C to 85°C		Tape and reel	4.3	CY74FCT257CTSOCT	FCT257C
	QSOP – Q	Tape and reel	5	CY74FCT257ATQCT	FT257-1
	QSOP – Q	Tape and reel	6	CY74FCT257TQCT	FT257

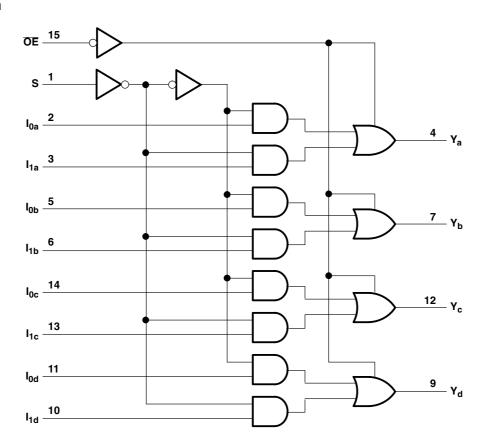
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

	INP		OUTPUT	
OE	S	I <sub>0</sub>	I <sub>1</sub>	Υ
Н	Χ	Χ	Х	Z
L	Н	Χ	L	L
L	Н	Χ	Н	Н
L	L	L	Χ	L
L	L	Н	Χ	Н

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

### logic diagram





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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	0.5 V to 7 V
DC input voltage range	0.5 V to 7 V
DC output voltage range	0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 1): Q package	90°C/W
SO package	57°C/W
Ambient temperature range with power applied, T <sub>A</sub>	–65°C to 135°C
Storage temperature range, T <sub>stq</sub>	65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

### recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
$V_{CC}$	Supply voltage	4.75	5	5.25	٧
$V_{IH}$	High-level input voltage	2			٧
$V_{IL}$	Low-level input voltage			8.0	٧
I <sub>OH</sub>	High-level output current			-32	mA
I <sub>OL</sub>	Low-level output current			64	mA
T <sub>A</sub>	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



### CY74FCT257T QUAD 2-INPUT MULTIPLEXER WITH 3-STATE OUTPUTS

SCCS019D - MAY 1994 - REVISED NOVEMBER 2001

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V <sub>IK</sub>	$V_{CC} = 4.75,$	$V_{CC} = 4.75$ , $I_{IN} = -18 \text{ mA}$					V
V <sub>OH</sub>	$V_{CC} = 4.75,$	$I_{OH} = -32 \text{ mA}$		2			٧
V <sub>OL</sub>	$V_{CC} = 4.75,$	$I_{OL} = 64 \text{ mA}$			0.3	0.55	V
$V_{hys}$	All inputs				0.2		V
I <sub>I</sub>	$V_{CC} = 5.25 \text{ V},$	V <sub>IN</sub> = 5.25 V				5	μΑ
I <sub>IH</sub>	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 2.7 \text{ V}$				±1	μΑ
I <sub>IL</sub>	$V_{CC} = 5.25 V$ ,			±1	μΑ		
l <sub>OZH</sub>	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 2.7 V				10	μΑ
l <sub>OZL</sub>	$V_{CC} = 5.25 \text{ V},$	V <sub>OUT</sub> = 0.5 V				-10	μΑ
l <sub>OS</sub> ‡	$V_{CC} = 5.25 \text{ V},$	$V_{OUT} = 0 V$		-60	-120	-225	mA
l <sub>off</sub>	$V_{CC} = 0 V$ ,	V <sub>OUT</sub> = 4.5 V				±1	μΑ
I <sub>CC</sub>	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$ ,	$V_{IN} \ge V_{CC} - 0.2 V$		0.1	0.2	mA
$\Delta I_{CC}$	$V_{CC} = 5.25 \text{ V}, V_{IN} = 3$	$8.4 \text{ V}$ , $f_1 = 0$ , Outputs open			0.5	2	mA
I <sub>CCD</sub> ¶		put switching at 50% duty of $V = V_{IN} \ge V_{CC} = 0.2 \text{ V}$	ycle, Outputs open,		0.06	0.12	mA/ MHz
		One input switching at f <sub>1</sub> = 10 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	
. #	$V_{CC} = 5.25 \text{ V},$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1	2.4	A
I <sub>C</sub> #	Outputs open,  OE = GND	Four bits switching at f <sub>1</sub> = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4	mA
		at 50% duty cycle	V <sub>IN</sub> = 3.4 V or GND		1.7	5.4	
C <sub>i</sub>					5	10	pF
Co					9	12	pF

<sup>&</sup>lt;sup>†</sup> Typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

Where:

I<sub>C</sub> = Total supply current

I<sub>CC</sub> = Power-supply current with CMOS input levels

 $\Delta I_{CC}$  = Power-supply current for a TTL high input ( $V_{IN}$  = 3.4 V)

 $D_H$  = Duty cycle for TTL inputs high  $N_T$  = Number of TTL inputs at  $D_H$ 

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

f<sub>0</sub> = Clock frequency for registered devices, otherwise zero

f<sub>1</sub> = Input signal frequency

N<sub>1</sub> = Number of inputs changing at f<sub>1</sub>

All currents are in milliamperes and all frequencies are in megahertz.

| Values for these conditions are examples of the I<sub>CC</sub> formula.



<sup>\*</sup> Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

 $<sup>\</sup>S$  Per TTL-driven input ( $V_{IN} = 3.4 \text{ V}$ ); all other inputs at  $V_{CC}$  or GND

<sup>¶</sup> This parameter is derived for use in total power-supply calculations.

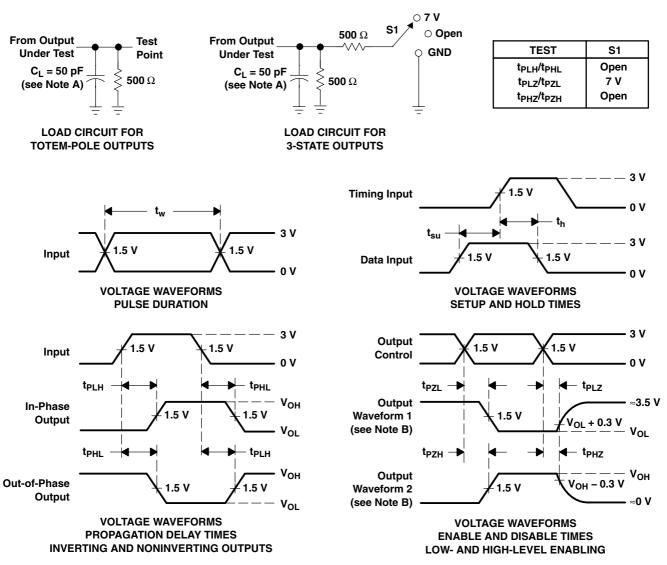
<sup>&</sup>lt;sup>#</sup>  $I_C$  =  $I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD}(f_0/2 + f_1 \times N_1)$ 

## CY74FCT257T **QUAD 2-INPUT MULTIPLEXER** WITH 3-STATE OUTPUTS SCCS019D - MAY 1994 - REVISED NOVEMBER 2001

### switching characteristics over operating free-air temperature range (see Figure 1)

DADAMETED	FROM	TO (OUTPUT)	CY74F0	CT257T	CY74FC	Г257АТ	CY74FC	LINUT	
PARAMETER	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	1	Υ	1.5	6	1.5	5	1.5	4.3	
t <sub>PHL</sub>			1.5	6	1.5	5	1.5	4.3	ns
t <sub>PLH</sub>		Y	1.5	10.5	1.5	7	1.5	5.2	
t <sub>PHL</sub>	S		1.5	10.5	1.5	7	1.5	5.2	ns
t <sub>PZH</sub>	Δ <del>.</del>	V	1.5	8.5	1.5	7	1.5	6	
t <sub>PZL</sub>	ŌĒ	Y	1.5	8.5	1.5	7	1.5	6	ns
t <sub>PHZ</sub>	ŌĒ	. Y	1.5	6	1.5	5.5	1.5	5	
t <sub>PLZ</sub>			1.5	6	1.5	5.5	1.5	5	ns

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms









10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CY74FCT257ATD	ACTIVE	SOIC	D	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT257AT	Samples
CY74FCT257ATQCT	ACTIVE	SSOP	DBQ	16	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT257-1	Samples
CY74FCT257CTSOC	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT257C	Samples
CY74FCT257TQCT	ACTIVE	SSOP	DBQ	16	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FT257	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE**: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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### **PACKAGE OPTION ADDENDUM**

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### PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

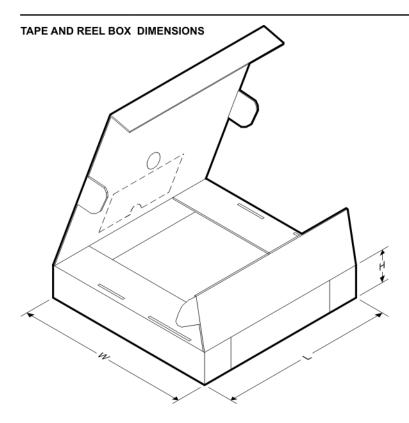
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT257ATQCT	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
CY74FCT257TQCT	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1

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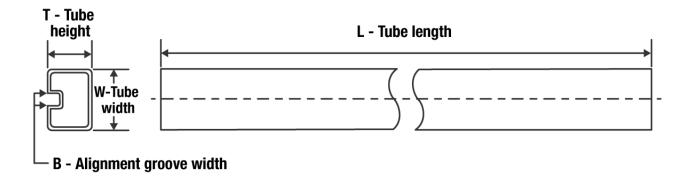
#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT257ATQCT	SSOP	DBQ	16	2500	340.5	338.1	20.6
CY74FCT257TQCT	SSOP	DBQ	16	2500	340.5	338.1	20.6

### PACKAGE MATERIALS INFORMATION

www.ti.com 5-Jan-2022

### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CY74FCT257ATD	D	SOIC	16	40	507	8	3940	4.32
CY74FCT257CTSOC	DW	SOIC	16	40	506.98	12.7	4826	6.6

### D (R-PDS0-G16)

### PLASTIC SMALL OUTLINE



NOTES:

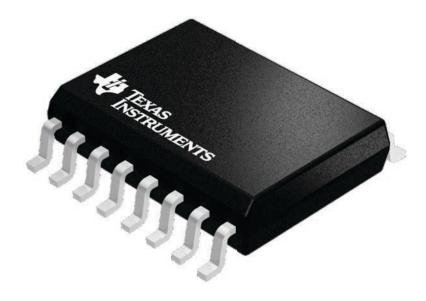
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



7.5 x 10.3, 1.27 mm pitch

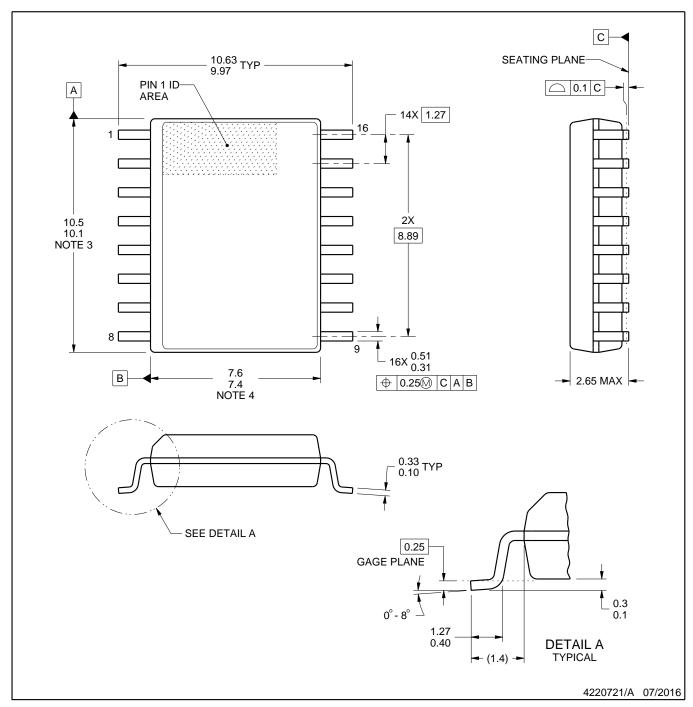
SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





SOIC



#### NOTES:

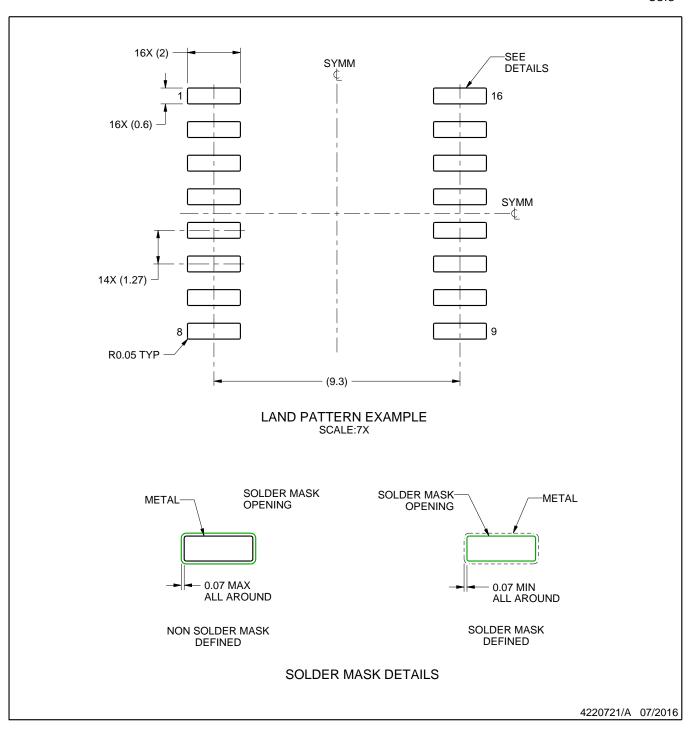
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
- 5. Reference JEDEC registration MS-013.



SOIC



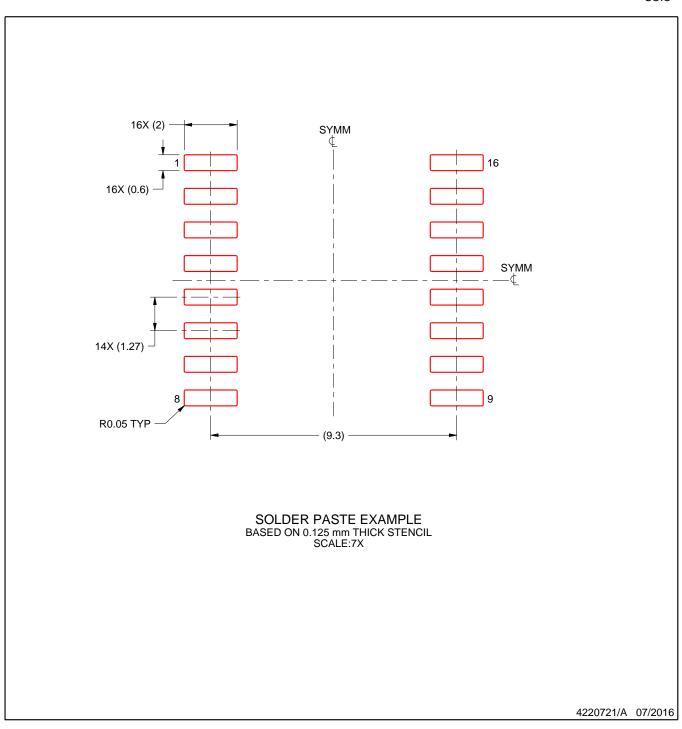
### NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



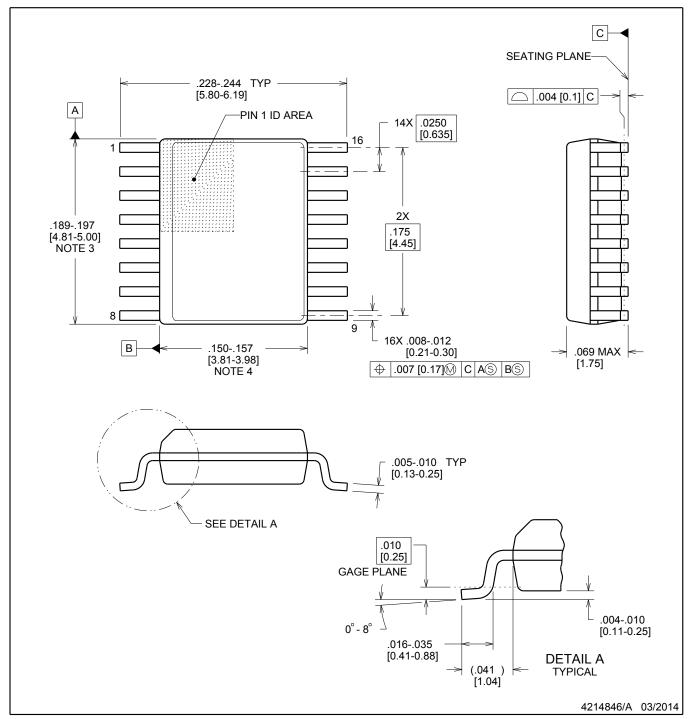
#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SHRINK SMALL-OUTLINE PACKAGE

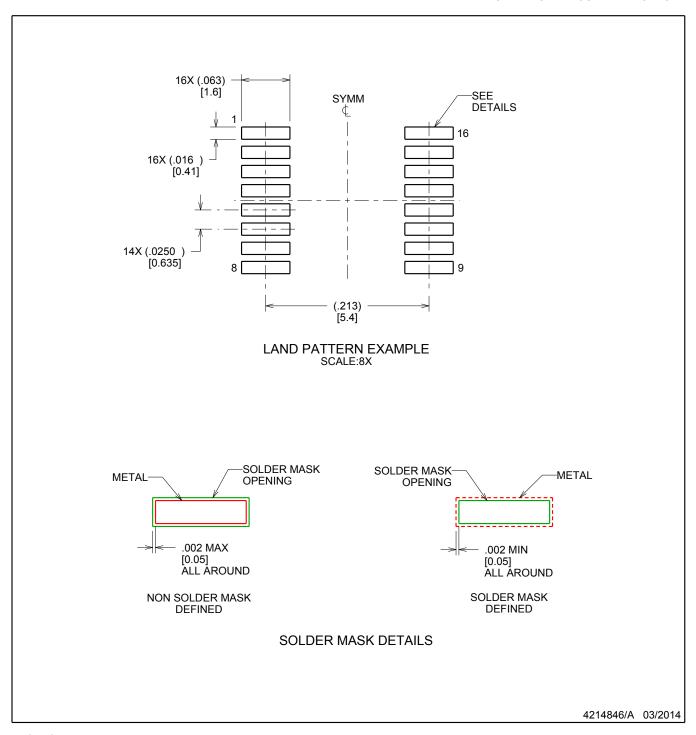


### NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MO-137, variation AB.



SHRINK SMALL-OUTLINE PACKAGE



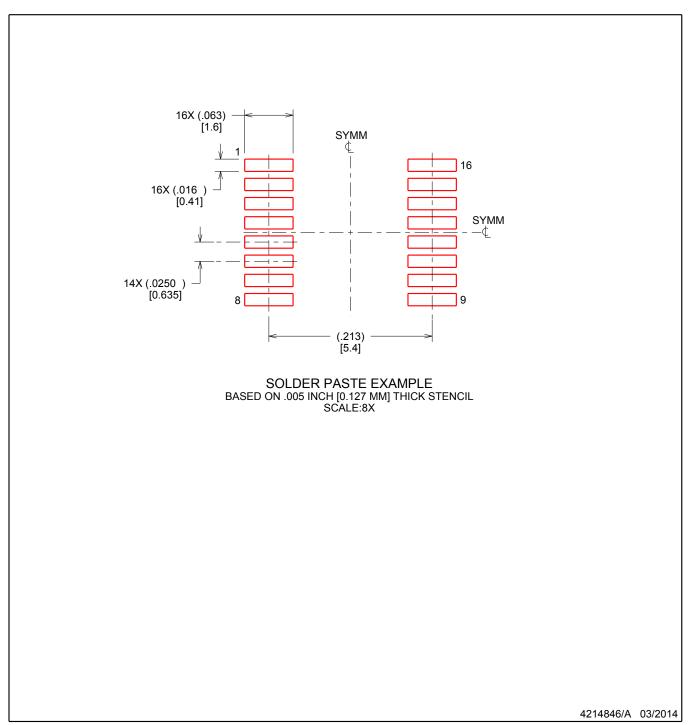
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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